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January 2014

FQD12N20L

N-Channel QFET® MOSFET

200 V, 9.0 A, 280 mΩ

Description

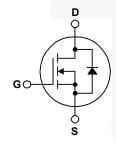
This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state

• Low Gate Charge (Typ. 16 nC) resistance, and to provide superior switching performance • Low Crss (Typ. 17 pF) and high avalanche energy strength. These devices are suitable for switched mode power supplies, active power • 100% Avalanche Tested factor correction (PFC), and electronic lamp ballasts.

Features

- 9.0 A, 200 V, $R_{DS(on)}$ = 280 m Ω (Max.) @ V_{GS} = 10 V, $I_D = 4.5 A$





Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol	Parameter	FQD12N20LTM	Unit
V_{DSS}	Drain-Source Voltage	200	V
I _D	Drain Current - Continuous (T _C = 25°C)	9.0	А
	- Continuous (T _C = 100°C)	5.7	Α
I _{DM}	Drain Current - Pulsed (N	ote 1) 36	Α
V _{GSS}	Gate-Source Voltage	± 20	V
E _{AS}	Single Pulsed Avalanche Energy (N	ote 2) 210	mJ
I _{AR}	Avalanche Current (N	ote 1) 9.0	A
E _{AR}	Repetitive Avalanche Energy (N	ote 1) 5.5	mJ
dv/dt	Peak Diode Recovery dv/dt (N	ote 3) 5.5	V/ns
P _D	Power Dissipation (T _A = 25°C) *	2.5	W
	Power Dissipation (T _C = 25°C)	55	W
	- Derate above 25°C	0.44	W/°C
T _J , T _{STG}	Operating and Storage Temperature Range	-55 to +150	°C
T _L	Maximum lead temperature for soldering, 1/8" from case for 5 seconds	300	°C

Thermal Characteristics

Symbol	Parameter	FQD12N20LTM	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	2.27	
D	Thermal Resistance, Junction to Ambient (Minimum Pad of 2-oz Copper), Max.	110	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (*1 in ² Pad of 2-oz Copper), Max.	50	

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FQD12N20LTM	FQD12N20L	DPAK	Tape and Reel	330 mm	16 mm	2500 units

Electrical Characteristics

T_C = 25°C unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Uni
Off Cha	aracteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0 V, I _D = 250 μA	200			V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	I _D = 250 μA, Referenced to 25°C		0.14		V/°(
I _{DSS}		V _{DS} = 200 V, V _{GS} = 0 V			1	μΑ
	Zero Gate Voltage Drain Current	V _{DS} = 160 V, T _C = 125°C			10	μΑ
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = 20 V, V _{DS} = 0 V			100	n/
I _{GSSR}	Gate-Body Leakage Current, Reverse	V _{GS} = -20 V, V _{DS} = 0 V			-100	n <i>P</i>
V _{GS(th)}	Gate Threshold Voltage Static Drain-Source	$V_{DS} = V_{GS}, I_D = 250 \mu A$ $V_{GS} = 10 \text{ V}, I_D = 4.5 \text{ A}$	1.0	 0.22	2.0	V
On Cha	racteristics					
$R_{DS(on)}$	Static Drain-Source On-Resistance	$V_{GS} = 10 \text{ V}, I_D = 4.5 \text{ A}$ $V_{GS} = 5 \text{ V}, I_D = 4.5 \text{ A}$		0.22 0.25	0.28	Ω
9 _{FS}	Forward Transconductance	$V_{DS} = 30 \text{ V}, I_D = 4.5 \text{ A}$		11.6		S
Dynami	ic Characteristics					
C _{iss}	Input Capacitance	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V},$		830	1080	pF
C _{oss}	Output Capacitance	f = 1.0 MHz		120	155	pF
C _{rss}	Reverse Transfer Capacitance			17	22	pF
Switchi	ing Characteristics					
t _{d(on)}	Turn-On Delay Time	V_{DD} = 100 V, I_{D} = 11.6 A, R_{G} = 25 Ω		15	40	ns
t _r	Turn-On Rise Time			190	390	ns
t _{d(off)}	Turn-Off Delay Time			60	130	ns

Drain-Source Diode Characteristics and Maximum Ratings

I _S	Maximum Continuous Drain-Source Diode Forward Current				9.0	Α
I _{SM}	Maximum Pulsed Drain-Source Diode Forward Current				36	Α
V_{SD}	Drain-Source Diode Forward Voltage V _{GS} = 0 V, I _S = 9.0 A				1.5	V
t _{rr}	Reverse Recovery Time	$V_{GS} = 0 \text{ V, } I_{S} = 11.6 \text{ A,}$		128		ns
Q _{rr}	Reverse Recovery Charge $dI_F / dt = 100 \text{ A/}\mu\text{s}$			0.56		μС

 $V_{GS} = 5 V$

 $V_{DS} = 160 \text{ V}, I_{D} = 11.6 \text{ A},$

(Note 4)

120

16

2.8

7.6

250

21

ns

nC

nC

nC

 Q_g

 Q_gs

 Q_{gd}

- Notes. The second of the seco

Turn-Off Fall Time

Total Gate Charge

Gate-Source Charge

Gate-Drain Charge

Typical Characteristics

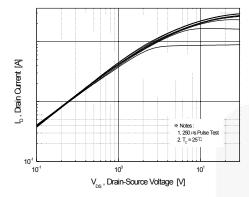


Figure 1. On-Region Characteristics

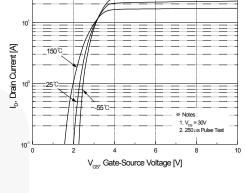


Figure 2. Transfer Characteristics

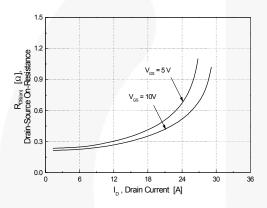


Figure 3. On-Resistance Variation vs.
Drain Current and Gate Voltage

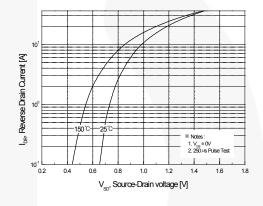


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

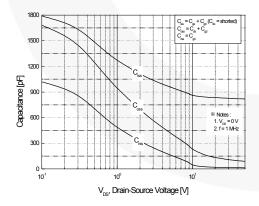


Figure 5. Capacitance Characteristics

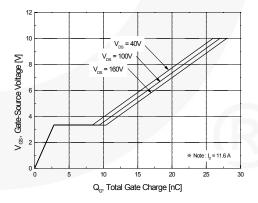


Figure 6. Gate Charge Characteristics

Typical Characteristics (Continued)

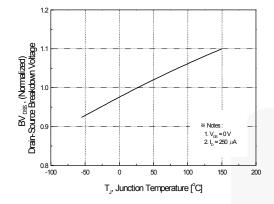


Figure 7. Breakdown Voltage Variation vs. Temperature

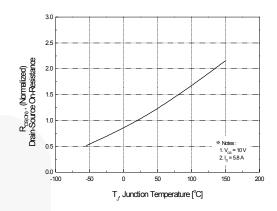


Figure 8. On-Resistance Variation vs. Temperature

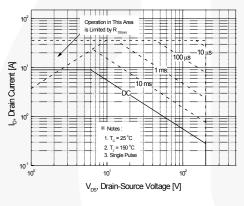


Figure 9. Maximum Safe Operating Area

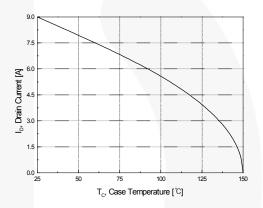


Figure 10. Maximum Drain Current vs. Case Temperature

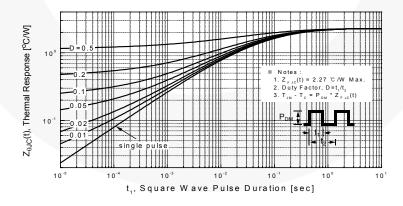


Figure 11. Transient Thermal Response Curve

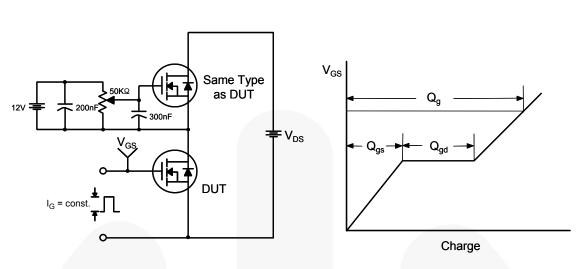


Figure 12. Gate Charge Test Circuit & Waveform

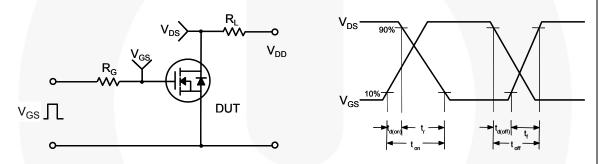


Figure 13. Resistive Switching Test Circuit & Waveforms

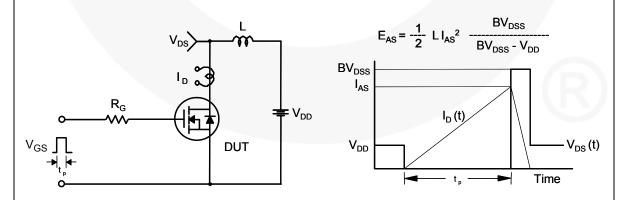
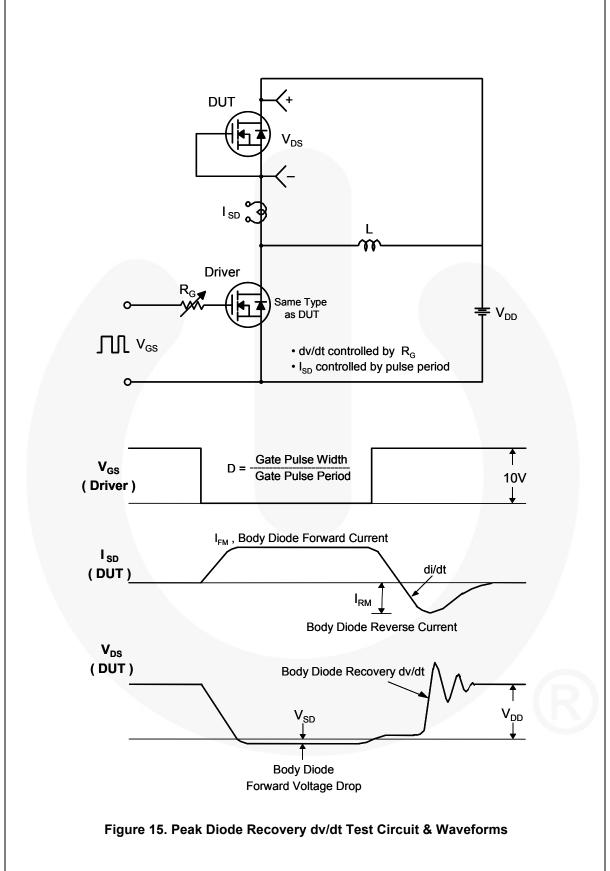


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms



Mechanical Dimensions

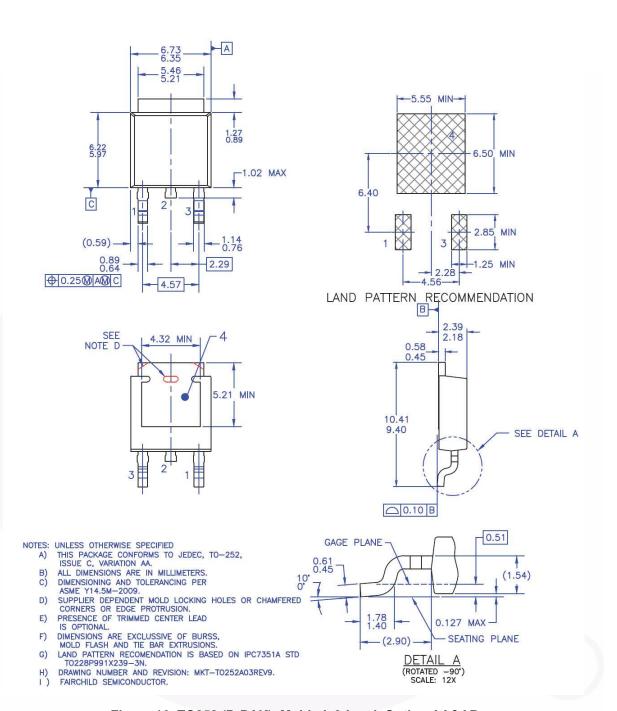


Figure 16. TO252 (D-PAK), Molded, 3-Lead, Option AA&AB

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